

- ★ 100% EAS Guaranteed
- ★ Green Device Available
- ★ Super Low Gate Charge
- ★ Excellent CdV/dt effect decline
- ★ Advanced high cell density Trench technology

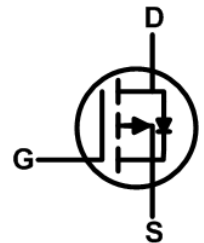
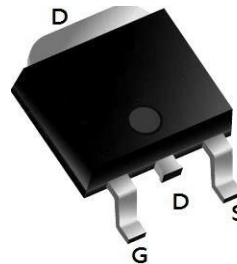
Product Summary


| BVDSS | RDSON | ID |
|-------|-------|------|
| -30V | 7.5mΩ | -60A |

Description

The XXW60P03 is the highest performance trench P-ch MOSFETs with extreme high cell density, which provide excellent RDSON and gate charge for most of the synchronous buck converter applications .

The XXW60P03 meet the RoHS and Green Product requirement, 100% EAS guaranteed with full function reliability approved.

TO252 Pin Configuration

Absolute Maximum Ratings (T_A = 25°C, unless otherwise noted)

| Parameter | | Symbol | Value | Unit |
|--|-----------------------|-----------------------------------|------------|------|
| Drain-Source Voltage | | V _{DS} | -30 | V |
| Gate-Source Voltage | | V _{GS} | ±20 | V |
| Continuous Drain Current | T _C =25°C | I _D | -60 | A |
| | T _C =100°C | | -32 | |
| Pulsed Drain Current ¹ | | I _{DM} | -200 | A |
| Single Pulse Avalanche Energy ² | | EAS | 80 | mJ |
| Total Power Dissipation | T _C =25°C | P _D | 43.1 | W |
| Operating Junction and Storage Temperature Range | | T _J , T _{STG} | -55 to 150 | °C |

Thermal Characteristics

| Parameter | Symbol | Value | Unit |
|--|------------------|-------|------|
| Thermal Resistance from Junction-to-Ambient ³ | R _{θJA} | 70 | °C/W |
| Thermal Resistance from Junction-to-Case | R _{θJC} | 2.9 | °C/W |

Electrical Characteristics (T_J = 25°C, unless otherwise noted)

| Parameter | Symbol | Test Conditions | Min. | Typ. | Max. | Unit |
|--|----------------------------|--|------|------|------|------|
| Static Characteristics | | | | | | |
| Drain-Source Breakdown Voltage | V_{(BR)DSS} | V _{GS} = 0V, I _D = -250μA | -30 | - | - | V |
| Gate-body Leakage current | I_{GSS} | V _{DS} = 0V, V _{GS} = ±20V | - | - | ±100 | nA |
| Zero Gate Voltage Drain Current | T _J =25°C | V _{DS} = -30V, V _{GS} = 0V | - | - | -1 | μA |
| | T _J =100°C | | - | - | -100 | |
| Gate-Threshold Voltage | V_{GS(th)} | V _{DS} = V _{GS} , I _D = -250μA | -1 | -1.5 | -2.5 | V |
| Drain-Source on-Resistance ⁴ | R_{DS(on)} | V _{GS} = -10V, I _D = -15A | - | 7.5 | 14 | mΩ |
| | | V _{GS} = -4.5V, I _D = -10A | - | 10.5 | 22 | |
| Forward Transconductance ⁴ | g_{fs} | V _{DS} = -10V, I _D = -15A | - | 44 | - | S |
| Dynamic Characteristics⁵ | | | | | | |
| Input Capacitance | C_{iss} | V _{DS} = -15V, V _{GS} = 0V, f = 1MHz | - | 2503 | - | pF |
| Output Capacitance | C_{oss} | | - | 315 | - | |
| Reverse Transfer Capacitance | C_{rss} | | - | 279 | - | |
| Gate Resistance | R_g | f = 1MHz | - | 10.5 | - | Ω |
| Switching Characteristics⁵ | | | | | | |
| Total Gate Charge | Q_g | V _{GS} = -10V, V _{DS} = -15V, I _D = -15A | - | 30 | - | nC |
| Gate-Source Charge | Q_{gs} | | - | 5 | - | |
| Gate-Drain Charge | Q_{gd} | | - | 7.5 | - | |
| Turn-on Delay Time | t_{d(on)} | V _{GS} = -10V, V _{DD} = -15V, R _G = 2.5Ω, I _D = -15A | - | 14.1 | - | ns |
| Rise Time | t_r | | - | 20 | - | |
| Turn-off Delay Time | t_{d(off)} | | - | 94 | - | |
| Fall Time | t_f | | - | 65 | - | |
| Drain-Source Body Diode Characteristics | | | | | | |
| Diode Forward Voltage ⁴ | V_{SD} | I _S = -1A, V _{GS} = 0V | - | - | -1.2 | V |
| Continuous Source Current | T _C =25°C | I_S | - | - | -60 | A |

Notes:

1. Repetitive rating, pulse width limited by junction temperature T_{J(MAX)}=150°C.
2. The EAS data shows Max. rating . The test condition is V_{DD}= -25V, L=0.1mH, I_{AS}= -40A.

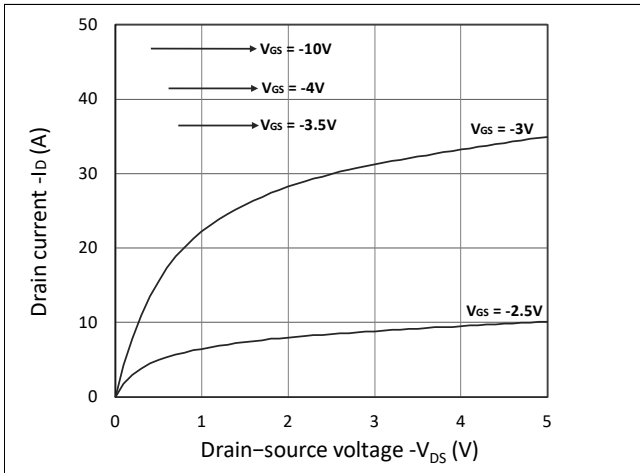
Typical Characteristics


Figure 1. Output Characteristics

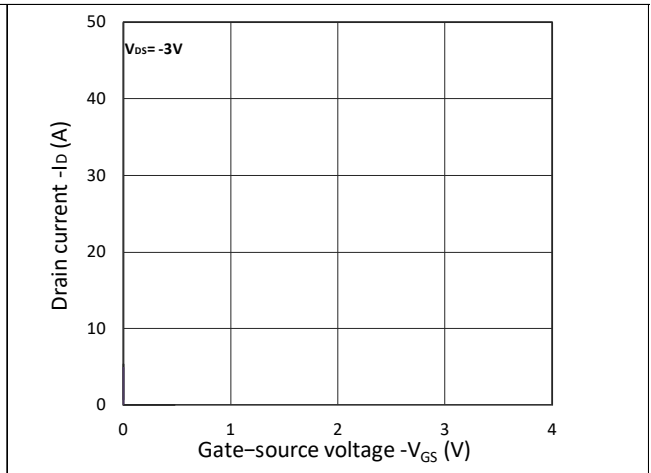


Figure 2. Transfer Characteristics

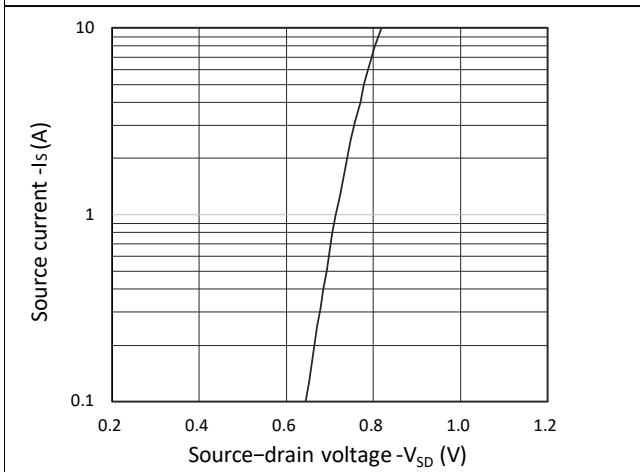
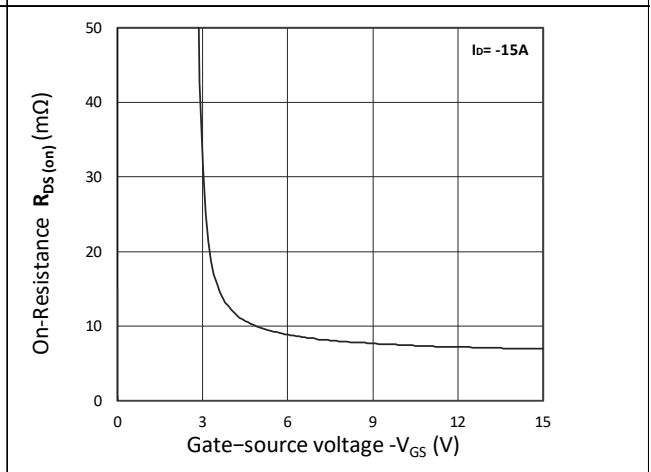
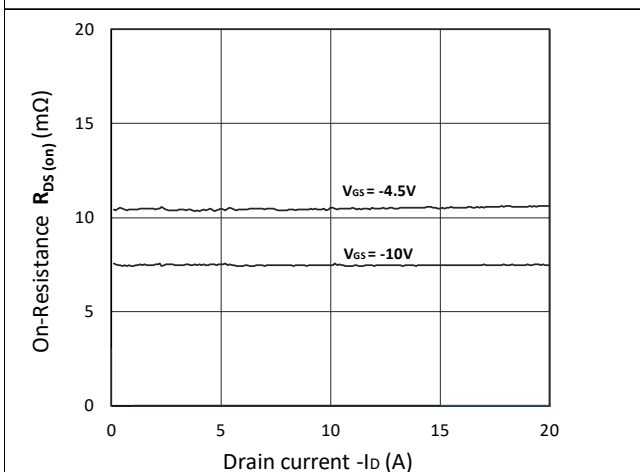
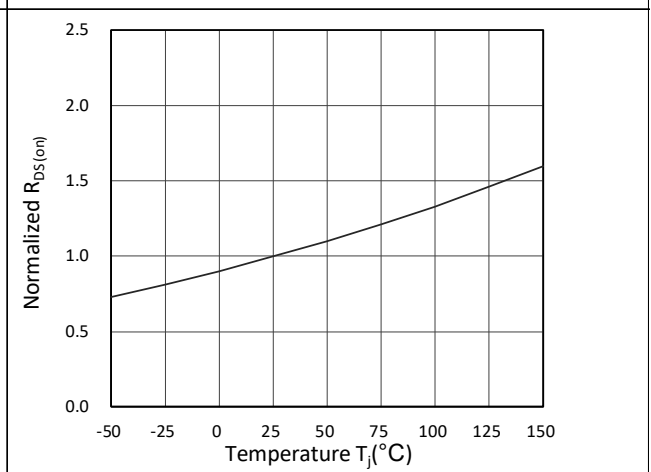


Figure 3. Forward Characteristics of Reverse


 Figure 4. $R_{DS(on)}$ vs. V_{GS}

 Figure 5. $R_{DS(on)}$ vs. I_D

 Figure 6. Normalized $R_{DS(on)}$ vs. Temperature

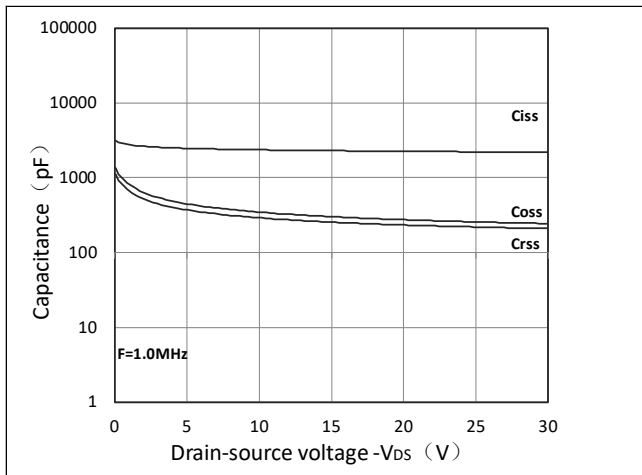


Figure 7. Capacitance Characteristics

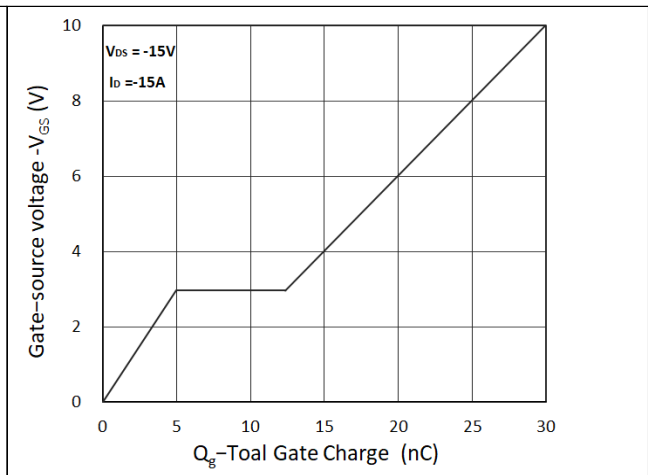


Figure 8. Gate Charge Characteristics

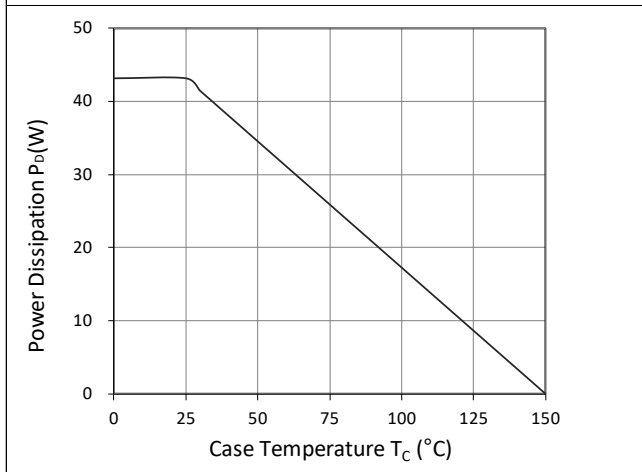


Figure 9. Power Dissipation

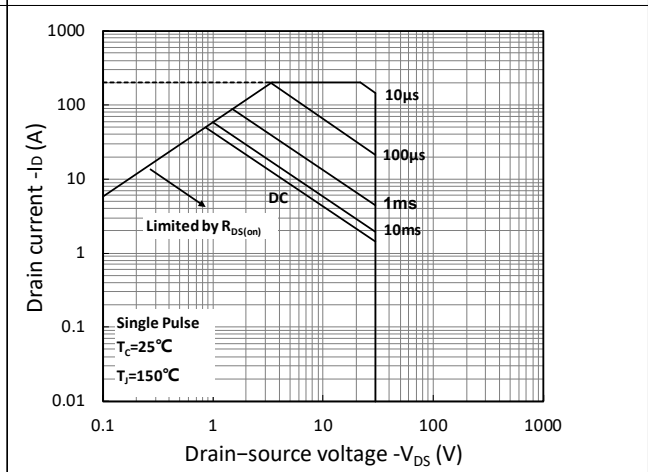


Figure 10. Safe Operating Area

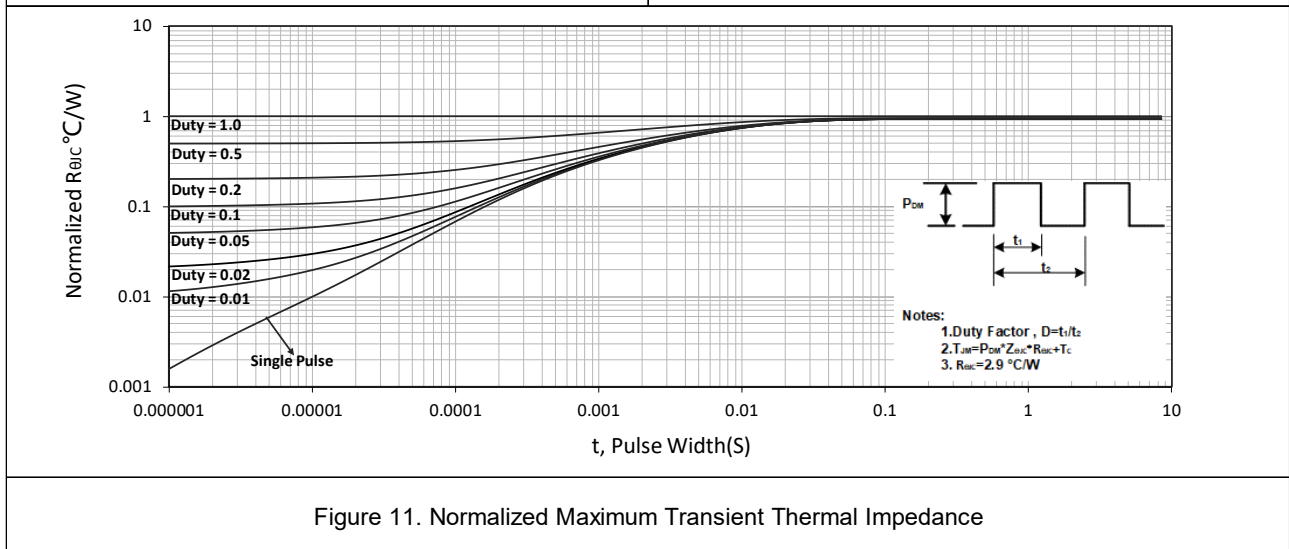
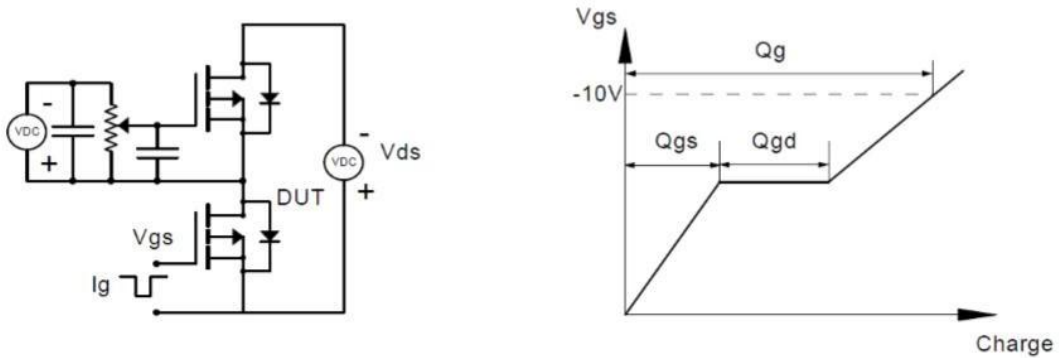
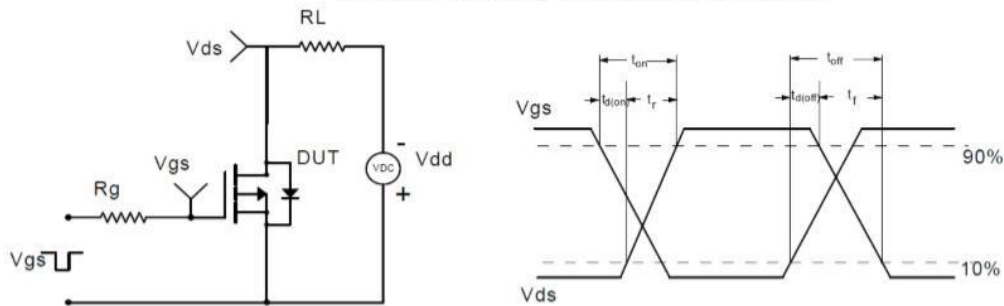
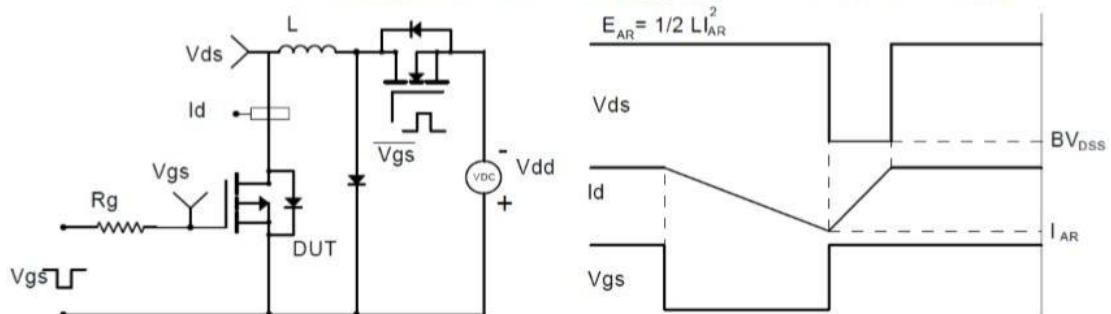
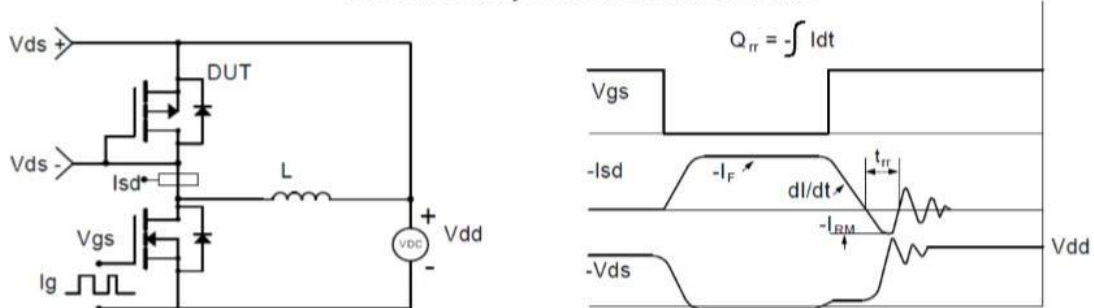
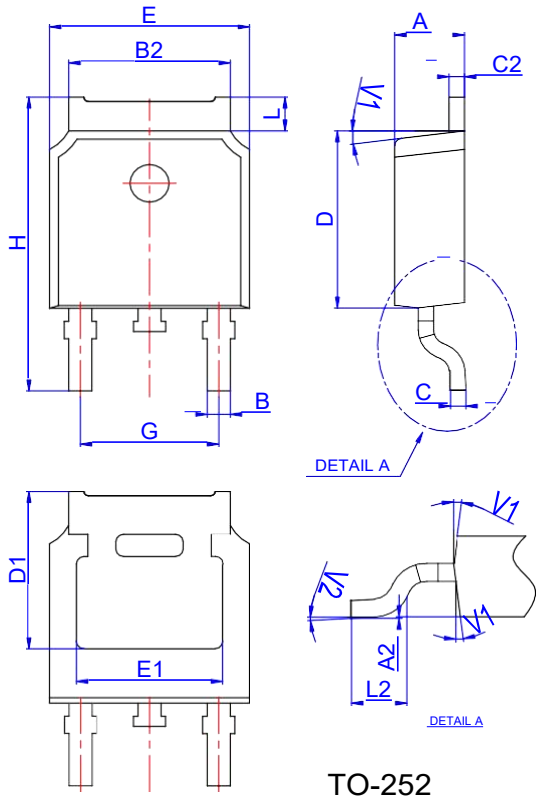
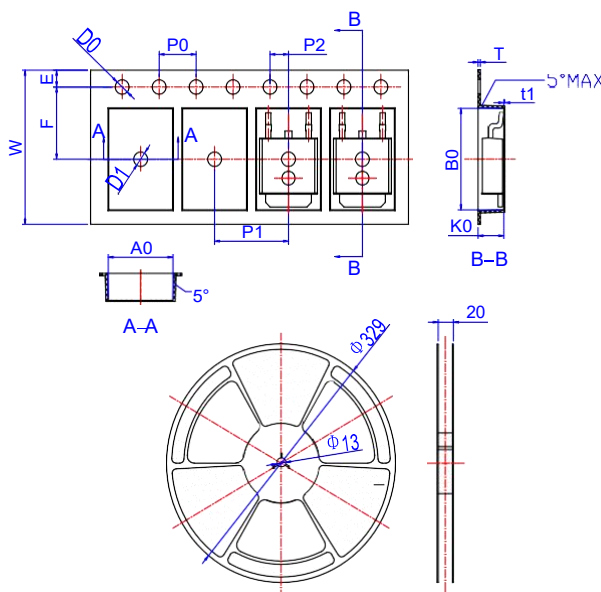


Figure 11. Normalized Maximum Transient Thermal Impedance

Test Circuit
Gate Charge Test Circuit & Waveform

Resistive Switching Test Circuit & Waveforms

Unclamped Inductive Switching (UIS) Test Circuit & Waveforms

Diode Recovery Test Circuit & Waveforms


Package Mechanical Data TO 252


| Ref. | Dimensions | | | | | |
|------|-------------|------|-------|----------|------|-------|
| | Millimeters | | | Inches | | |
| | Min. | Typ. | Max. | Min. | Typ. | Max. |
| A | 2.10 | | 2.50 | 0.083 | | 0.098 |
| A2 | 0 | | 0.10 | 0 | | 0.004 |
| B | 0.66 | | 0.86 | 0.026 | | 0.034 |
| B2 | 5.18 | | 5.48 | 0.202 | | 0.216 |
| C | 0.40 | | 0.60 | 0.016 | | 0.024 |
| C2 | 0.44 | | 0.58 | 0.017 | | 0.023 |
| D | 5.90 | | 6.30 | 0.232 | | 0.248 |
| D1 | 5.30REF | | | 0.209REF | | |
| E | 6.40 | | 6.80 | 0.252 | | 0.268 |
| E1 | 4.63 | | | 0.182 | | |
| G | 4.47 | | 4.67 | 0.176 | | 0.184 |
| H | 9.50 | | 10.70 | 0.374 | | 0.421 |
| L | 1.09 | | 1.21 | 0.043 | | 0.048 |
| L2 | 1.35 | | 1.65 | 0.053 | | 0.065 |
| V1 | | 7° | | | 7° | |
| V2 | 0° | | 6° | 0° | | 6° |

Reel Specification-TO-252-4R


| Ref. | Dimensions | | | | | |
|------|-------------|-------|-------|--------|-------|-------|
| | Millimeters | | | Inches | | |
| | Min. | Typ. | Max. | Min. | Typ. | Max. |
| W | 15.90 | 16.00 | 16.10 | 0.626 | 0.630 | 0.634 |
| E | 1.65 | 1.75 | 1.85 | 0.065 | 0.069 | 0.073 |
| F | 7.40 | 7.50 | 7.60 | 0.291 | 0.295 | 0.299 |
| D0 | 1.40 | 1.50 | 1.60 | 0.055 | 0.059 | 0.063 |
| D1 | 1.40 | 1.50 | 1.60 | 0.055 | 0.059 | 0.063 |
| P0 | 3.90 | 4.00 | 4.10 | 0.154 | 0.157 | 0.161 |
| P1 | 7.90 | 8.00 | 8.10 | 0.311 | 0.315 | 0.319 |
| P2 | 1.90 | 2.00 | 2.10 | 0.075 | 0.079 | 0.083 |
| A0 | 6.85 | 6.90 | 7.00 | 0.270 | 0.271 | 0.276 |
| B0 | 10.45 | 10.50 | 10.60 | 0.411 | 0.413 | 0.417 |
| K0 | 2.68 | 2.78 | 2.88 | 0.105 | 0.109 | 0.113 |
| T | 0.24 | | 0.27 | 0.009 | | 0.011 |
| t1 | 0.10 | | | 0.004 | | |
| 10P0 | 39.80 | 40.00 | 40.20 | 1.567 | 1.575 | 1.583 |